# **Plastic Point Source Infrared Emitting Diode OP245PS**



### Features:

- Point source irradiance pattern
- Side-looking package for space-limited applications
- Wavelength matched to silicon's peak response
- Higher power output than GaAs at equivalent drive currents
- Fast switching speed



## **Description:**

Each OP245PS device is an infrared emitting diode with a 850 nm GaAlAs chip, molded in a clear IR-transmissive side-looking epoxy package. This package makes these devices ideal for PCBoard mounted slotted switches and for mounted interrupt detectors.

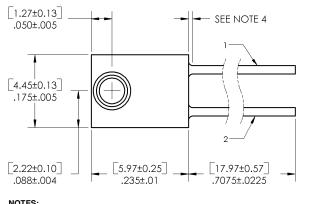
The stable forward  $V_F$  vs  $T_A$  characteristic make them suitable for applications that have limited voltage, such as battery operation; whereas, the low  $T_{\rm B}/T_{\rm F}$  makes them ideal for high-speed operations.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

## **Applications:**

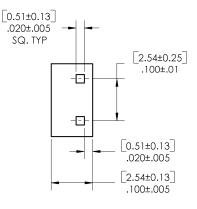
- Space-limited applications Mounted interrupt detector
- PCBoard mounted slotted switch
- High-speed applications

Ordering Information							
Part Number			Total Beam Angle	Lead Length (min.)			
OP245PS	850 nm	Flat	±18°	0.5" / 12.7 mm			



#### NOTES:

- 1. OUTSIDE DISCRETE SHELL IS POLYSULFONE P1700-11 CLEAR.
- 2. THIS LED IS BUILT WITH A 0.011" X 0.011" GaAIAs CHIP. 3. MAX ALLOWABLE EPOXY MENSCUS IS 0.010".



1 ANODE 2 CATHODE DIMENSIONS ARE IN: [MILLIMETERS]



Pin #	LED				
1	Anode				
2	Cathode				



CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' Vibra-Tite for thread-locking. Vibra-Tite evaporates fast without causing structural failure in OPTEK'S molded plastics

OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.



## Absolute Maximum Ratings (T<sub>A</sub> = 25°C unless otherwise noted)

Storage and Operating Temperature Range	-40° C to +100° C
Reverse Voltage	2.0 V
Continuous Forward Current	50 mA
Peak Forward Current	1.0 A
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260 ° C <sup>(1)</sup>
Power Dissipation	100 mW <sup>(2)</sup>

## Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

SYMBO L	PARAMETER	ΜΙΝ	ТҮР	МАХ	UNITS	TEST CONDITIONS
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Input Diode

E <sub>E (APT)</sub>	Apertured Radiant Incidence	0.12	-	0.8	mW/cm <sup>2</sup>	$I_F = 20 \text{ mA}^{(.3)}$
V <sub>F</sub>	Forward Voltage	1.2	-	1.7	V	I <sub>F</sub> = 20 mA
I <sub>R</sub>	Reverse Current	-	10	-	μA	V <sub>R</sub> = 2 V
$\lambda_{P}$	Wavelength at Peak Emission	-	850	-	nm	I <sub>F</sub> = 20 mA
В	Spectral Bandwidth between Half Power Points	-	50	-	nm	I <sub>F</sub> = 20 mA
$\theta_{HP}$	Emission Angle at Half Power Points	-	±18°	-	Degree	I <sub>F</sub> = 20 mA
tr	Output Rise Time	-	10	-	ns	$I_{F(PK)} = 20 \text{ mA}, PW = 10 \ \mu s, D.C. = 10\%$
t <sub>f</sub>	Output Fall Time	-	10	-	ns	

Notes:

1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.

2. Derate linearly 1.33 mW/° C above 25° C.

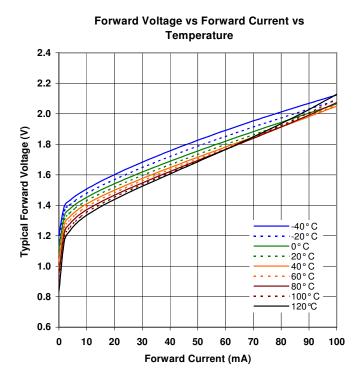
 E<sub>E(APT)</sub> is a measurement of the average apertured radiant energy incident upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (16.6 mm) from the lens tip. E<sub>E(APT)</sub> is not necessarily uniform within the measured area.

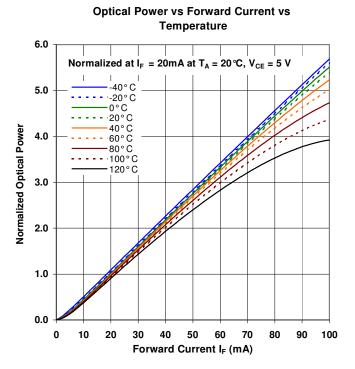
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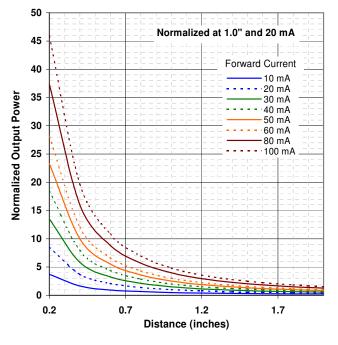


OP245PS





**Distance vs Power vs Forward Current** 



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